

1. General description

Planar passivated SCR with sensitive gate in a SOT223 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

2. Features and benefits

- Sensitive gate
- Planar passivated for voltage ruggedness and reliability
- Direct triggering from low power drivers and logic ICs
- Surface mountable package

3. Applications

- Ground Fault Circuit Interrupters (GFCI)
- · General purpose switching and phase control
- Ignition circuits, CDI for 2- and 3-wheelers
- Motor control e.g. small kitchen appliances

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	850	V
V _{RRM}	repetitive peak reverse voltage		-	-	850	V
I _{T(AV)}	average on-state current	half sine wave; $T_{sp} \le 98 \text{ °C}$	-	-	0.8	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{sp} ≤ 98 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	-	1.1	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4; Fig. 5</u>	-	-	11	A
Static chara	acteristics		· · ·			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	15	-	50	μA

5. Pinning information

-	-	

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	4	А - 🗲 К
2	А	anode		Ġ sym037
3	G	gate		Symust
4	А	mb; connected to anode	☐1	

6. Ordering information

Table 3. Ordering information						
Type number	Package	kage				
	Name	Description	Version			
NCR100W-10L	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

7. Marking

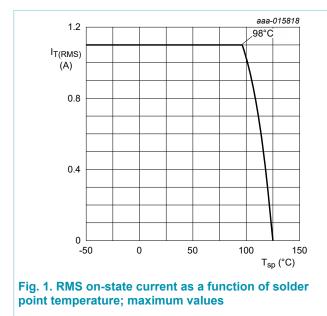
Table 4. Marking codes					
	Type number	Marking code			
	NCR100W-10L	10010L			

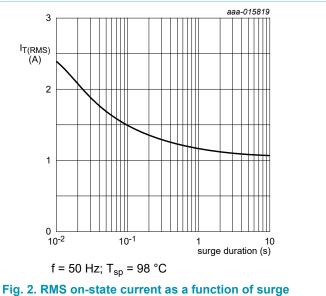
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	850	V
V _{RRM}	repetitive peak reverse voltage		-	850	V
I _{T(AV)}	average on-state current	half sine wave; $T_{sp} \le 98 \text{ °C}$	-	0.8	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{sp} \le 98$ °C; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	1.1	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	11	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	12.1	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.605	A²s
dI _T /dt	rate of rise of on-state current	I _G = 0.1 mA	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

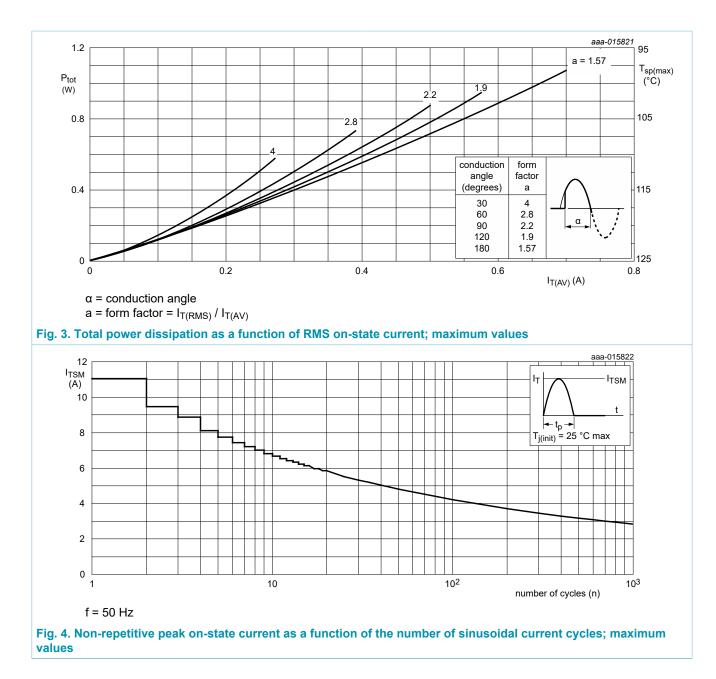




duration; maximum values

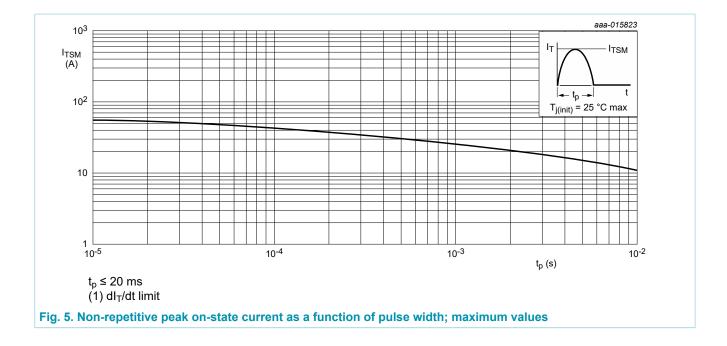
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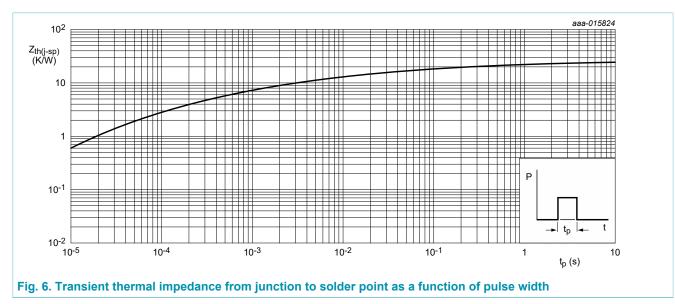
SCR



NCR100W-10L

9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	half cycle; <u>Fig. 6</u>	-	-	25	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	printed circuit board mounted; minimum footprint; in free air	-	130	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	M	n Typ	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V_D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7	15	i –	50	μA
IL	latching current	V_D = 12 V; I _G = 0.5 mA; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 8	-	-	6	mA
I _H	holding current	V_D = 12 V; T _j = 25 °C; R _{GK(ext)} = 1 k Ω ; Fig. 9	-	-	3	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 11</u>	-	0.5	0.8	V
		V _D = 850 V; I _T = 10 mA; T _j = 125 °C; <u>Fig. 11</u>	0.3	3 0.5	-	V
I _D	off-state current	V_D = 850 V; $R_{GK(ext)}$ = 1 k Ω ; T_j = 125 °C	-	0.05	1	mA
I _R	reverse current	V_R = 850 V; T _j = 125 °C; R _{GK(ext)} = 1 kΩ	-	0.05	1	mA
Dynamic ch	narateristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 569 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform	10	0 -	-	V/µs
t _{gt}	gate-controlled turn-on time	$\begin{split} I_{TM} &= 2 \text{ A}; V_D = 850 \text{V}; \text{I}_G = 10 \text{mA}; \text{d} \text{I}_G \text{/} \\ \text{d} \text{t} &= 0.1 \text{A} / \mu \text{s}; \text{T}_j = 25 ^\circ \text{C} \end{split}$	-	2	-	μs
tq	commutated turn-off time	$V_{DM} = 569 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{TM} = 1.6 \text{ A};$ $V_{R} = 35 \text{ V}; (dI_{T}/dt)_{M} = 30 \text{ A}/\mu\text{s}; dV_{D}/$ $dt = 2 \text{ V}/\mu\text{s}; \text{ R}_{GK(ext)} = 1 \text{ k}\Omega; (V_{DM} = 67\% \text{ of } V_{DRM})$	-	100	-	μs

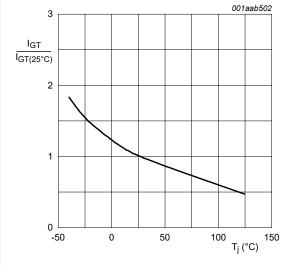
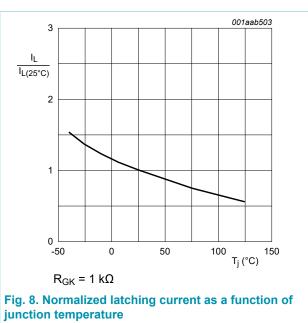
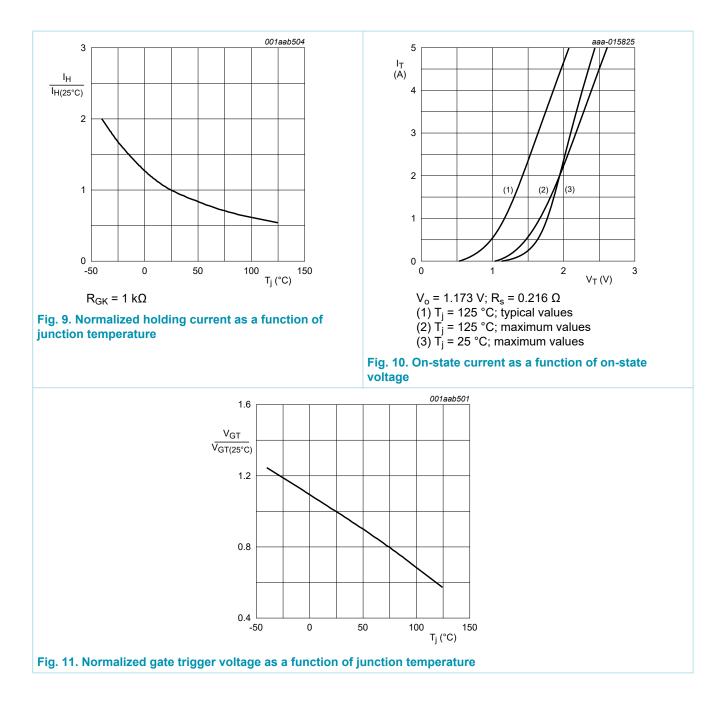


Fig. 7. Normalized gate trigger current as a function of junction temperature

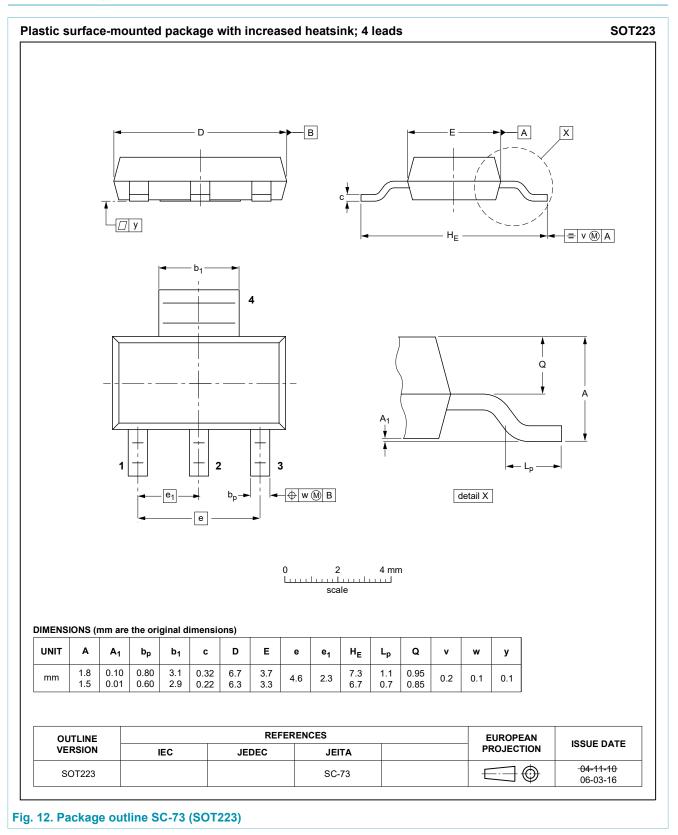


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SCR

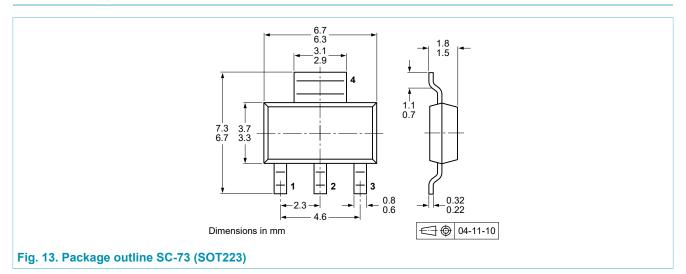


11. Package outline

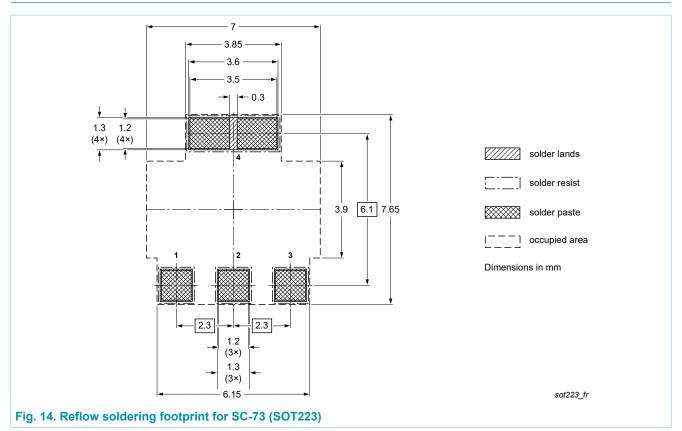


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12. Package outline (minimized)

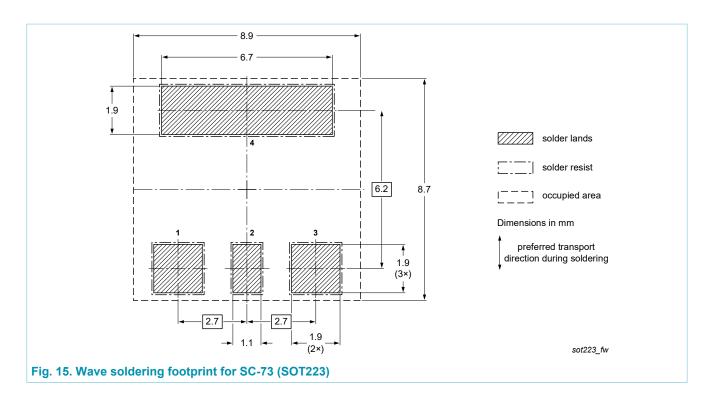


13. Soldering



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14. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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